

4-Pin Mini-Flat Phototransistor Optocoupler

Features

- High isolation 3750 VRMS
- DC/AC input with transistor output
- Operating temperature range 55 °C to 125 °C
- DMC[®] structure
- RoHS compliance
- REACH compliance
- Halogen free
- Regulatory Approvals
 - UL UL1577 (Pending Approval)
 - VDE EN60747-5-5 (Pending Approval)
 - CQC GB4943.1, GB8898 (Pending Approval)
 - IEC60065, IEC60950 (Pending Approval)

Description

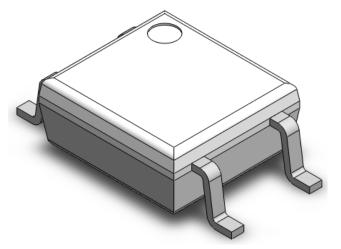
CT121GB series of general purpose optocoupler consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead Mini-Flat package.

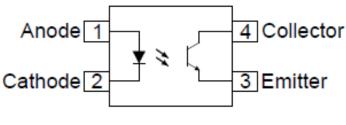
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline

Schematic





CT121



4-Pin Mini-Flat Phototransistor Optocoupler

Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
Viso	Isolation voltage	3750	V _{RMS}	
Ртот	Total power dissipation	200	mW	
Topr	Operating temperature	-55 ~ +125	°C	
Tstg	Storage temperature	-55 ~ +150	°C	
TsoL	Soldering temperature	260	°C	
Emitter				
I _F	Forward current	60	mA	
I _{F(TRANS)}	Peak transient current (≤1µs P.W,300pps)	1000	mA	
VR	Reverse voltage	6	V	
P _D	Emitter power dissipation	100	mW	
Detector	,			
Pc	Detector power dissipation	150	mW	
B _{VCEO}	Collector-Emitter Breakdown Voltage	80	V	
Bveco	Emitter-Collector Breakdown Voltage	6	V	
Ic	Collector Current	50	mA	



4-Pin Mini-Flat Phototransistor Optocoupler

Electrical Characteristics $T_A = 25$ °C (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
VF	Forward voltage	I _F =10mA	-	1.2	1.3	V	
I _R	Reverse Current	$V_R = 6V$	-	-	5	μΑ	
Cin	Input Capacitance	f= 1MHz	-	10	30	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
Bvceo	Collector-Emitter Breakdown	I _C = 100μA	80	-	-	V	
B _{VECO}	Emitter-Collector Breakdown	I _{EC} = 100μA	7	-	-	V	
	Collector-Emitter Dark Current	V _{CE} = 48V, I _F =0mA	-	-	100	nA	
ICEO	Collector-Emitter Dark Current	V _{CE} = 48V, I _F =0mA , Ta=85°C			50	uA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
OTD	Ownerst Transfer Datia	I _F = 5mA, V _{CE} = 5V	100		600	%	
CTR	Current Transfer Ratio	I _F = 1mA, V _{CE} = 0.4V	30	-	-	%	
	Collector-Emitter Saturation	I- 0m / I- 2.4m /		0.2	0.4	V	
VCE(SAT)	Voltage	I _F = 8mA, I _C = 2.4mA	-	0.2	0.4	V	
Rıo	Isolation Resistance	V _{IO} = 500V _{DC}	5x10 ¹⁰	-	-	Ω	
C _{IO}	Isolation Capacitance	f= 1MHz	-	0.25	1	pF	

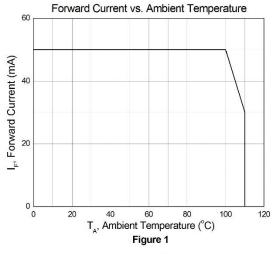
Switching Characteristics

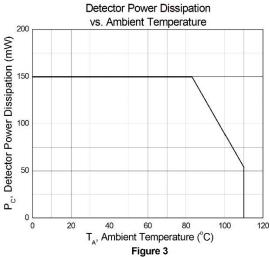
Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
t _r	Rise Time		-	5	16	0	
t _f	Fall Time	I _C = 2mA, V _{CE} = 2V	-	6	16	μS	
t _{on}	Turn-on time	R _L = 100Ω		8	20	0	
t _{off}	Turn-off time			7	20	μS	

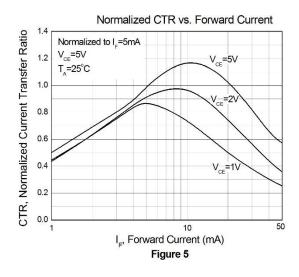


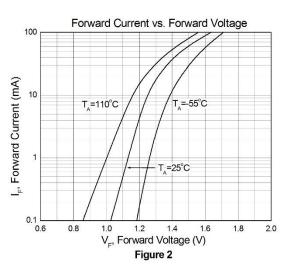
4-Pin Mini-Flat Phototransistor Optocoupler

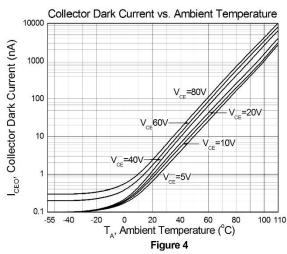
Typical Characteristic Curves

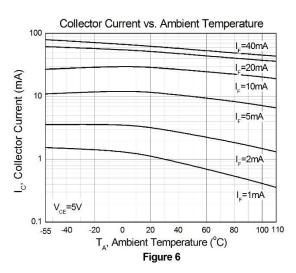








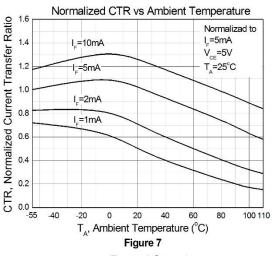


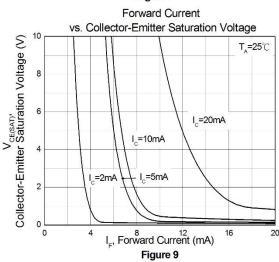


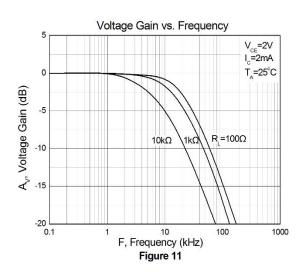


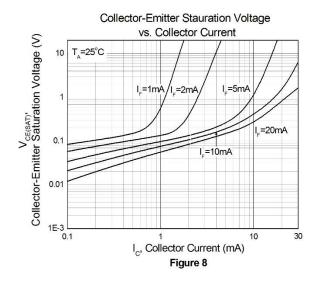
4-Pin Mini-Flat Phototransistor Optocoupler

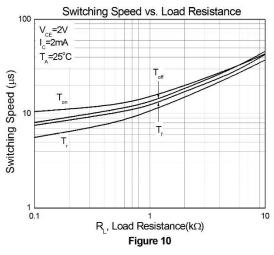
Typical Characteristic Curves







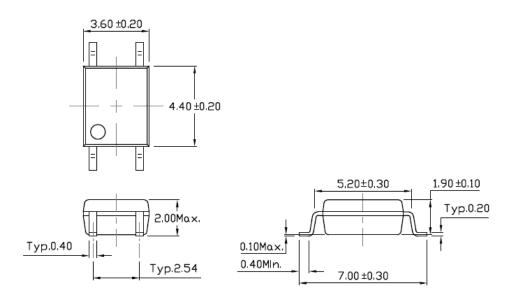




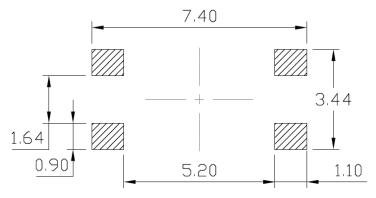


4-Pin Mini-Flat Phototransistor Optocoupler

Package Dimension Dimensions in mm unless otherwise stated



Recommended Solder Mask Dimensions in mm unless otherwise stated





4-Pin Mini-Flat Phototransistor Optocoupler

Marking Information



Note:

CT : Denotes "CT Micro"

121 : Part NumberGB : CTR Rank

V : VDE Safety Option (V or none)

Y : Fiscal Year WW : Work Week

K : Manufacturing Code

Ordering Information

CT121GB (V)(Y)

CT : Denotes "CT Micro"

121 : Part NumberGB : CTR Rank

V : VDE Safety Option (V or none)Y : Tape and reel option (T1 or T2)

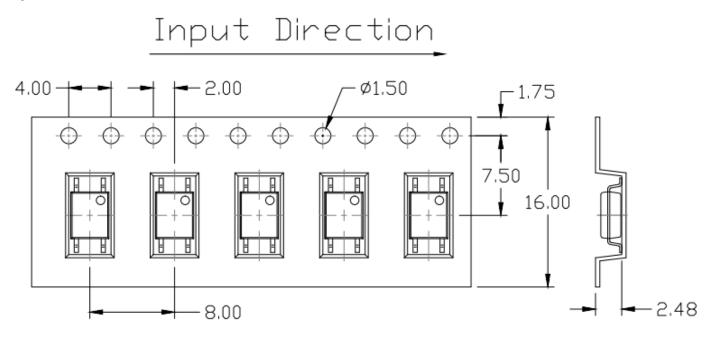
Option	Description	Quantity
T1	Surface Mount Lead Forming – With Option 1 Tapping	3000 Units/Reel
T2	Surface Mount Lead Forming – With Option 2 Tapping	3000 Units/Reel



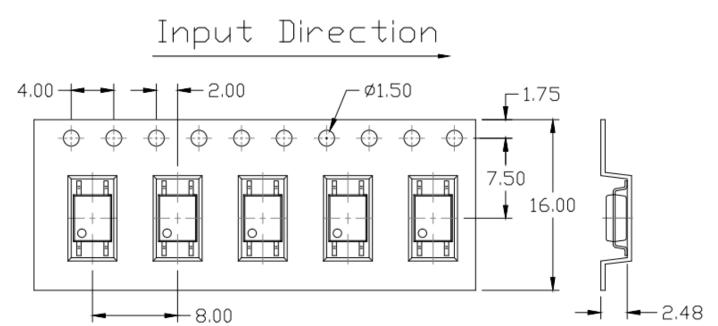
4-Pin Mini-Flat Phototransistor Optocoupler

Carrier Tape Specifications Dimensions in mm unless otherwise stated

Option T1



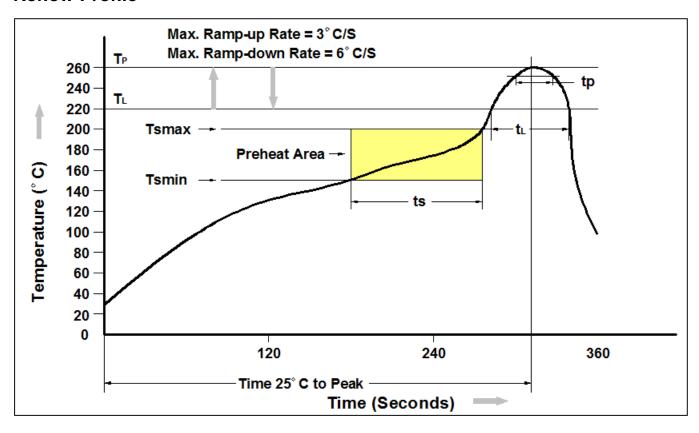
Option T2





4-Pin Mini-Flat Phototransistor Optocoupler

Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



4-Pin Mini-Flat Phototransistor Optocoupler

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